## NSN 5961-01-177-1329

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View Online at https://aerobasegroup.com/nsn/5961-01-177-1329 **Inclosure Material:** Metal **Overall Length:** 0.810 inches **Overall Height:** 0.190 inches **Overall Width:** 0.740 inches **Mounting Facility Quantity: Internal Configuration:** Point contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.5 emitter to base voltage, static, collector open and 45.0 collector to base voltage/static/emitter open and 45.0 collector-to-emitter substaining voltage, resistance between base and emitter **Current Rating Per Characteristic:** 5.00 milliamperes zero-gate-voltage source current preset **Transfer Ratio:** 15.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Test Data Document:** 21877-41450 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

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